RT3TAAM

Composite Transistor With Resistor For Switching Application Silicon Epitaxial Type

DESCRIPTION

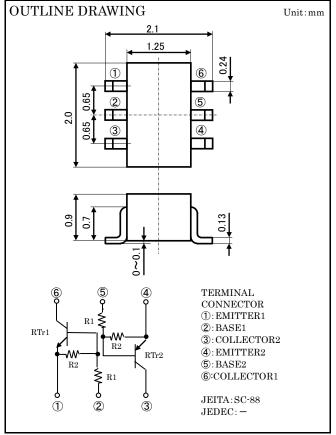
RT3TAAM is composite transistor built with RT1N151 chip and RT1P151 chip in SC-88 package.

FEATURE

Built-in bias resistor (R1=100k Ω , R2=100k Ω) Mini package for easy mounting

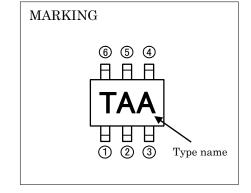
APPLICATION

Inverted circuit, Switching circuit, Interface circuit, Driver circuit



MAXIMUM RATING (Ta=25°C) (RTr1_NPN, RTr2_PNP)

SYMBOL	PARAMETER	RATING	UNIT	
Vcbo	Collector to Base voltage	50	V	
Vebo	Emitter to Base voltage	10	V	
VCEO	Collector to Emitter voltage	50	V	
VIN	Input voltage	40	V	
$I_{\mathbf{C}}$	Collector current	100	mA	
Icm	Peak Collector current	200	mA	
P_{T}	Total dissipation	200	mW	
Tj	Junction temperature	+150	°C	
$T_{ m stg}$	Storage temperature	-55~+150	°C	



 $\prescript{\text{MPNP built in transistor}}$ of "—"sign is abbreviation.

ELECTRICAL CHARACTERISTICS (Ta=25°C) (RTr1_NPN, RTr2_PNP)

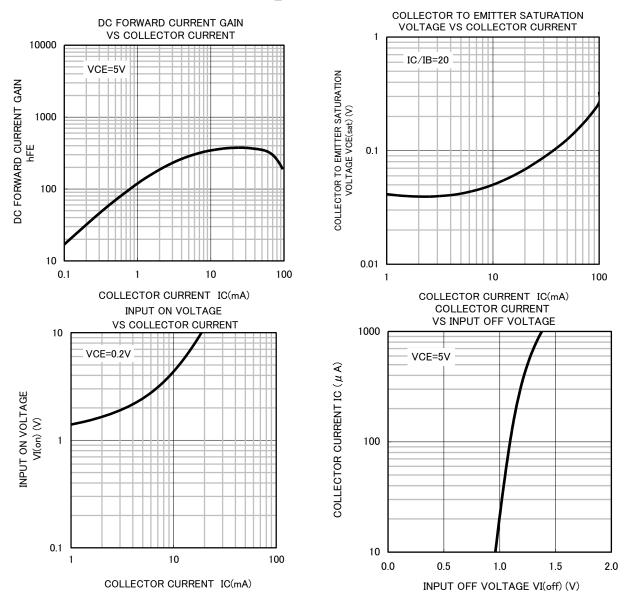
Symbol	Parameter	Test conditions		Limits			TT :4
				Min	Тур	Max	Unit
V(BR)CEO	Collector to Emitter breakdown voltage	nitter breakdown voltage I_{C} =100 μ A, R_{BE} = ∞		50	_	_	V
Icbo	Collector cut off current V_{CB} =50V, I_{E} =0		_	_	0.1	μΑ	
IEBO	$\begin{tabular}{lllllllllllllllllllllllllllllllllll$		18.8	25.0	36.3	μΑ	
$_{ m hFE}$	DC forward current gain	urrent gain V _{CE} =5V, I _C =5mA		82	_	_	_
V _{CE} (sat)	Collector to Emitter saturation voltage Ic=5mA, I _B =0.25mA		-	_	0.3	V	
VI(ON)	Input on voltage V_{CE} =0.2V, I_{C} =5mA		1	2.4	8.8	V	
V _I (OFF)	Input off voltage V_{CE} =5V, I_{C} =100 μ A		0.8	1.1	_	V	
R_1	Input resistor	_		-	100	_	$k\Omega$
R_2/R_1	Resistor ratio	_		0.8	1.0	1.2	_
$ m f_T$	Gain band width product	V _{CE} =6V, I _E =10mA	RTr1	_	200	_	MHa
			RTr2	1	150	_	$ m MH_{ m Z}$

XPNP built in transistor of "−"sign is abbreviation.

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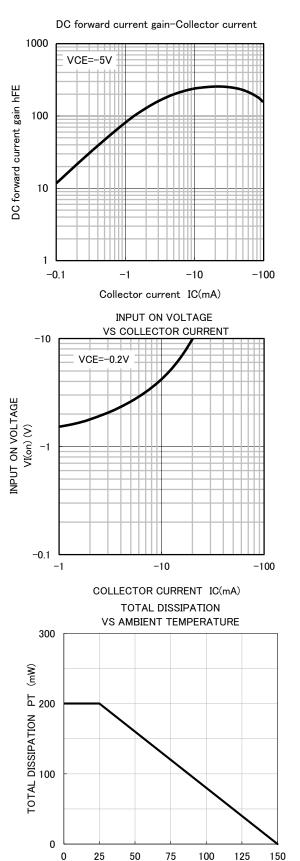
TYPICAL CHARACTERISTICS(Ta=25°C)(RTr1_NPN)



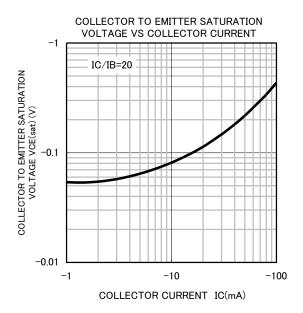
RT3TAAM

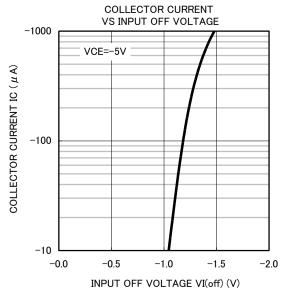
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TYPICAL CHARACTERISTICS(Ta=25°C)(RTr 2_PNP)



AMBIENT TEMPERATURE Ta (°C)





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